NSN 5962-01-445-3696

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-40.0/+85.0 degrees celsius
End Application:
F-15i
Features Provided:
Electrostatic sensitive
Inclosure Material:
Plastic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic and transistor-transistor logic
Criticality Code Justification:
Cbbl
Current Rating Per Characteristic:
10.00 microamperes reverse current, dc microamperes
Product Name:
5-volt only cmos flash perom
Voltage Rating And Type Per Characteristic:
4.5 volts power source and 5.5 volts power source
Capitance Rating Per Characteristic:
6.00 input picofarads
Time Rating Per Chacteristic:
90.00 nanoseconds write-cycle width
Memory Device Type:
Eprom
Terminal Type And Quantity:
32 beam lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A458a0